

### Features

- Wide 4V to 30V Operating Input Range
- 1.2A Continuous Output Current
- 1.4MHz Switching Frequency
- Short Protection with Hiccup-Mode
- Built-in Over Current Limit
- Built-in Over Voltage Protection
- Force-PWM Mode
- Internal Soft-Start
- 200mΩ/150mΩ Low RDS(ON) Internal Power
- MOSFETs
- Output Adjustable from 0.8V
- No Schottky Diode Required
- Integrated internal compensation
- Thermal Shutdown
- Available in SOT23-6 Package
- -40°C to +85°C Temperature Range

### Applications

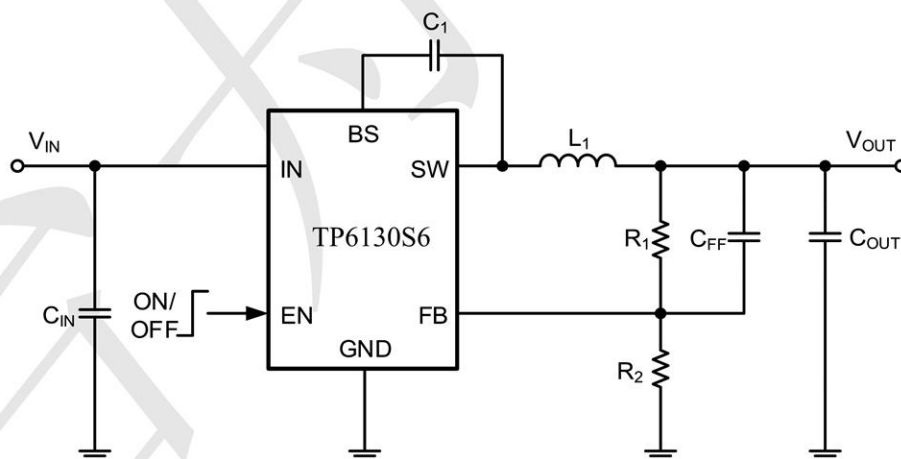
- Security Camera
- Consumer Electronic Device for automobile
- Portable DVD
- ADSL Modem, WLAN router
- Other 12V or double cell Li-ion battery

### General Description

The TP6130S6 is a high frequency, synchronous, rectified, step-down, switch-mode converter with internal power MOSFETs. It offers a very compact solution to achieve a 1.5A peak output current over a wide input supply range, with excellent load and line regulation.

The TP6130S6 requires a minimal number of readily available, external components and is available in a space saving SOT23-6 package.

### TYPICAL APPLICATION

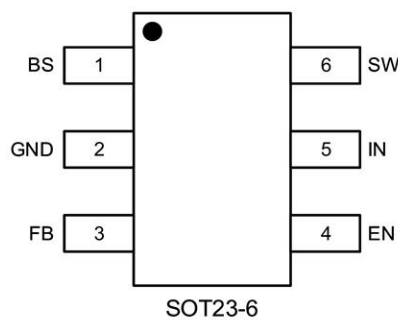


Basic Application Circuit

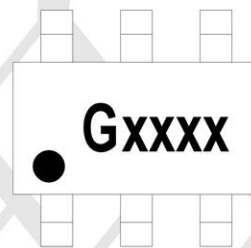
$$V_{OUT} = V_{FB} \times \frac{R1 + R2}{R2}$$

V <sub>OUT</sub>	R1	R2	L <sub>1MIN</sub>	L <sub>1TYP</sub>	L <sub>1MAX</sub>	C <sub>IN</sub>	C <sub>OUT</sub>
1V	2.5KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
1.05V	3.13KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
1.2V	5KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
1.5V	8.75KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
3.3V	31.25KΩ	10KΩ	3.3μH	3.3μH	4.7μH	20-47uF	20-68uF
5.0V	52.5KΩ	10KΩ	3.3μH	4.7μH	4.7μH	20-47uF	20-68uF

**PIN CONFIGURATION**



**Marking:**



“G” is Part Number, fixed

“xxxx” is internal code

Pin	Name	Function
1	BS	Bootstrap. A capacitor connected between SW and BS pins is required to form a floating supply across the high-side switch driver.
2	GND	GROUND Pin
3	FB	Adjustable Version Feedback input. Connect FB to the center point of the external resistor divider
4	EN	Drive this pin to a logic-high to enable the IC. Drive to a logic-low to disable the IC and enter micro-power shutdown mode.
5	IN	Power Supply Pin
6	SW	Switching Pin

**Absolute Maximum Rating** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

$V_{IN}$ , EN, Voltage .....	-0.3V to 36V	$V_{SW}$ Voltage .....	-0.3V to ( $V_{IN}+0.5V$ )
$V_{FB}$ Voltages .....	-0.3 to 6V	$V_{BS}$ Voltage .....	( $V_{sw}-0.3$ ) to ( $V_{sw}+5V$ )
Operating Temperature Range .....	$-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	Storage Temperature Range .....	$-65^{\circ}\text{C}$ to $150^{\circ}\text{C}$
Lead Temperature (Soldering, 10s) .....	$+300^{\circ}\text{C}$	Junction Temperature.....	$+125^{\circ}\text{C}$
ESD (Human Body Made) HMB.....	2KV	ESD (Machine Made) MM.....	200V

Note1: Exceeding these ratings may damage the device.

Note2: The device is not guaranteed to function outside of its operating conditions.

**Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

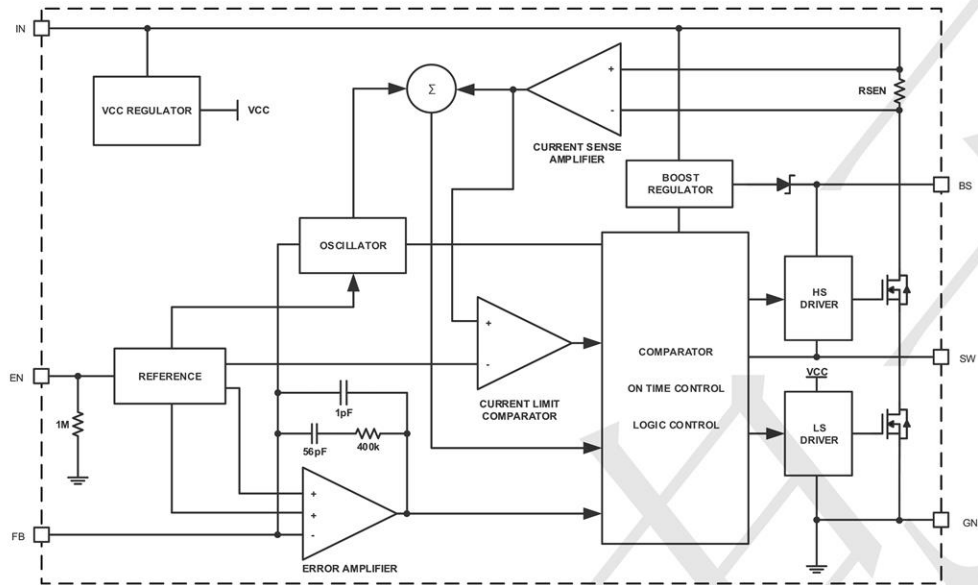
( $V_{IN}=12V$ ,  $V_{OUT}=5V$ ,  $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.)

Parameter	Test Conditions	Min	Typ	Max	Unit
Input Voltage Range		4		30	V
Supply Current in Operation	$V_{EN}=3.0V$ , $V_{FB}=1.1V$		0.4	0.6	mA
Supply Current in Shutdown	$V_{EN}=0$ or $EN = GND$			4	$\mu\text{A}$
Regulated Feedback Voltage	$T_A = 25^{\circ}\text{C}$ , $4V \leq V_{IN} \leq 18V$	0.791	0.807	0.823	V
High-Side Switch On-Resistance			200		m $\Omega$
Low-Side Switch On-Resistance			150		m $\Omega$
High-Side Switch Leakage Current	$V_{EN}=0V$ , $V_{SW}=12V$			1	$\mu\text{A}$
Upper Switch Current Limit	Minimum Duty Cycle		1.5		A
Oscillation Frequency		1.2	1.4	1.6	MHz
Maximum Duty Cycle	$V_{FB}=0.807V$	90	95		%
Minimum On-Time			60		nS
Minimum Off-Time			140		nS
EN up Threshold	$V_{EN}$ -Rising	1.05	1.15	1.25	V
EN Threshold Hysteresis			140		mV
Soft Start				1.2	mS
Thermal Shutdown			160		$^{\circ}\text{C}$
Thermal Hysteresis			20		$^{\circ}\text{C}$

Note (3): MOSFET on-resistance specifications are guaranteed by correlation to wafer level measurements.

Note (4): Thermal shutdown specifications are guaranteed by correlation to the design and characteristics analysis.

**BLOCK DIAGRAM**





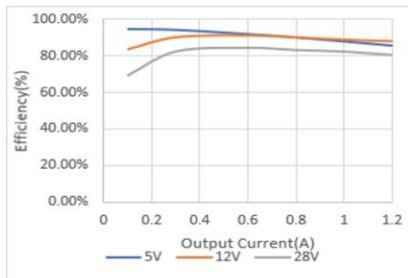
## Type Characteristics

Note (5): Performance waveforms are tested on the evaluation board.

Note (6):  $V_{IN}=12V$ ,  $V_{OUT}=3.3V$ ,  $T_A = +25^{\circ}C$ , unless otherwise noted.

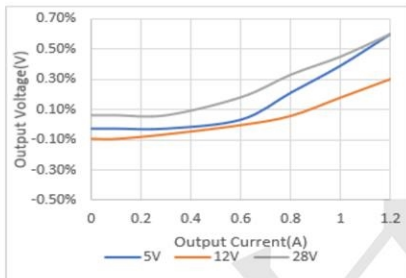
**Efficiency vs Load Current**

$V_{OUT} = 3.3V$



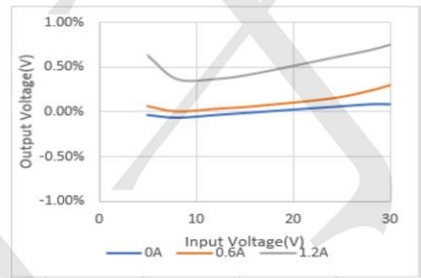
**Load Regulation**

$V_{OUT} = 3.3V$



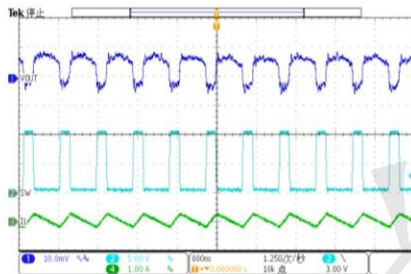
**Line Regulation**

$V_{OUT} = 3.3V$



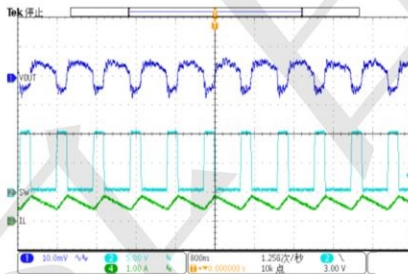
**Output Ripple Voltage**

$V_{IN}=12V$ ,  $V_{OUT}=3.3V$ ,  $I_{OUT}=0A$



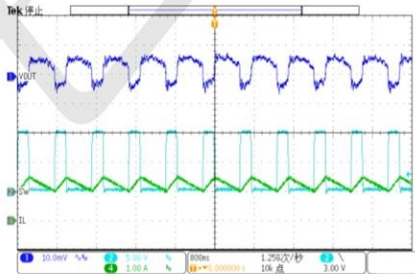
**Output Ripple Voltage**

$V_{IN}=12V$ ,  $V_{OUT}=3.3V$ ,  $I_{OUT}=0.6A$



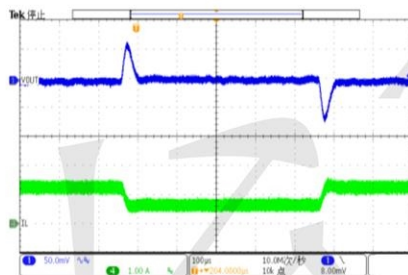
**Output Ripple Voltage**

$V_{IN}=12V$ ,  $V_{OUT}=3.3V$ ,  $I_{OUT}=1.2A$



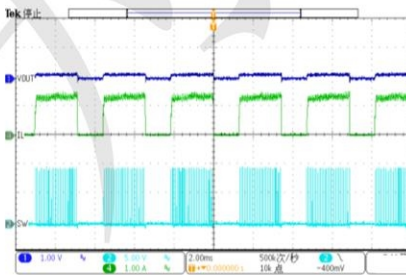
**Loop Response**

$V_{IN} = 12V$ ,  $V_{OUT} = 3.3V$ ,  $I_{INDUCTOR} = 0.6A-1.2A$



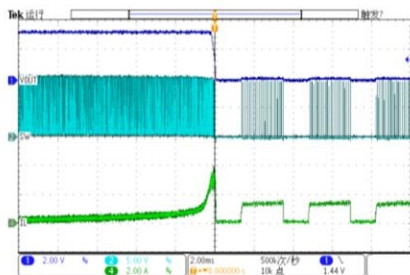
**Hiccup with Output Short**

$V_{IN} = 12V$ ,  $V_{OUT} = 3.3V$



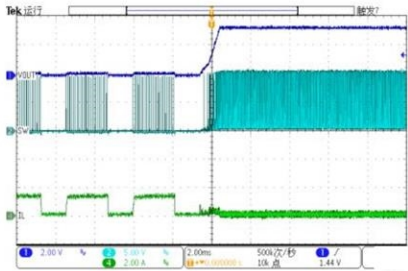
**Short Circuit Entry**

$V_{IN} = 12V$ ,  $V_{OUT} = 3.3V$



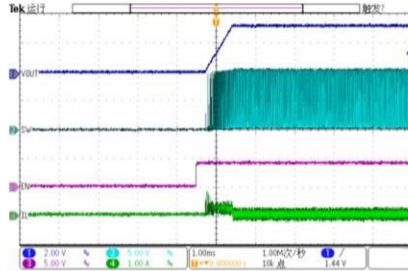
**Short Circuit Recovery**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V



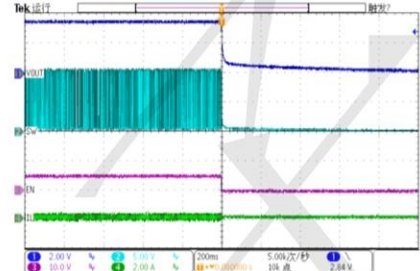
**Enable Startup at No Load**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V, I<sub>OUT</sub> = 0A



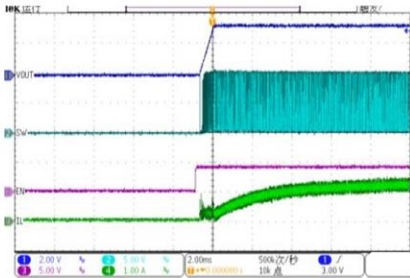
**Enable Shutdown at No Load**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V, I<sub>OUT</sub> = 0A



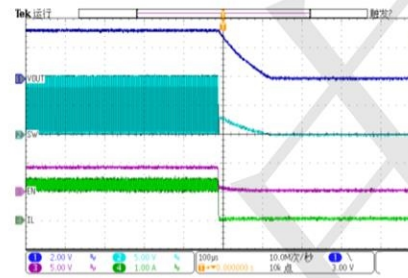
**Enable Startup at Full Load**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V, I<sub>OUT</sub> = 1.2A



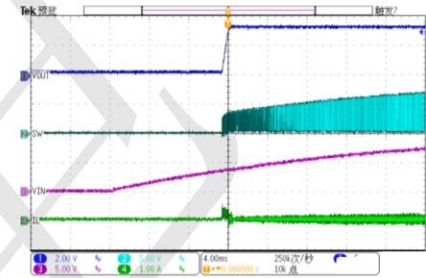
**Enable Shutdown at Full Load**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V, I<sub>OUT</sub> = 1.2A



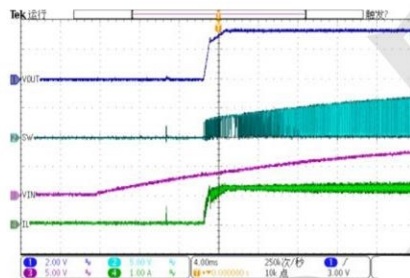
**Power Up at No Load**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V, I<sub>OUT</sub> = 0A



**Power Up at No Load**

V<sub>IN</sub> = 12V, V<sub>OUT</sub> = 3.3V, I<sub>OUT</sub> = 1.2A





## Functions Description

### Internal Regulator

The TP6130S6 is a current mode step down DC/DC converter that provides excellent transient response with no extra external compensation components. This device contains an internal, low resistance, high voltage power MOSFET, and operates at a high 1.4MHz operating frequency to ensure a compact, high efficiency design with excellent AC and DC performance.

### Error Amplifier

The error amplifier compares the FB pin voltage with the internal FB reference (VFB) and outputs a current proportional to the difference between the two. This output current is then used to charge or discharge the internal compensation network, which is used to control the power MOSFET current. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

### Internal Soft-Start

The soft-start is implemented to prevent the converter output voltage from overshooting during startup. When the chip starts, the internal circuitry generates a soft-start voltage (SS) ramping up from 0V to 0.807V. When it is lower than the internal reference (REF), SS overrides REF so the error amplifier uses SS as the reference. When SS is higher than REF, REF regains control. The SS time is internally max to 1.2ms.

### Over Current Protection & Hiccup

The TP6130S6 has cycle-by-cycle over current limit when the inductor current peak value exceeds the set current limit threshold. Meanwhile, output voltage starts to drop until FB is below the Under-Voltage (UV) threshold, typically 25% below the reference. Once a UV is triggered, the TP6130S6 enters hiccup mode to periodically restart the part. This protection mode is especially useful when the output is dead-short to ground. The average short circuit

current is greatly reduced to alleviate the thermal issue and to protect the regulator. The TP6130S6 exits the hiccup mode once the over current condition is removed.

### Startup and Shutdown

If both VIN and EN are higher than their appropriate thresholds, the chip starts. The reference block starts first, generating stable reference voltage and currents, and then the internal regulator is enabled. The regulator provides stable supply for the remaining circuitries. Three events can shut down the chip: EN low, VIN low and thermal shutdown. In the shutdown procedure, the signaling path is first blocked to avoid any fault triggering. The comp voltage and the internal supply rail are then pulled down. The floating driver is not subject to this shutdown command.

## Applications Information

### Setting the Output Voltage

TP6130S6 require an input capacitor, an output capacitor and an inductor. These components are critical to the performance of the device. TP6130S6 are internally compensated and do not require external components to achieve stable operation. The output voltage can be programmed by resistor divider.

$$V_{OUT} = V_{FB} \times \frac{R1 + R2}{R2}$$

V <sub>OUT</sub>	R1	R2	L1 <sub>MIN</sub>	L1 <sub>TYP</sub>	L1 <sub>MAX</sub>	C <sub>IN</sub>	C <sub>OUT</sub>
1V	2.5KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
1.05V	3.13KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
1.2V	5KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
1.5V	8.75KΩ	10KΩ	2.2μH	2.2μH	4.7μH	20-47uF	20-68uF
3.3V	31.25KΩ	10KΩ	3.3μH	3.3μH	4.7μH	20-47uF	20-68uF
5.0V	52.5KΩ	10KΩ	3.3μH	4.7μH	4.7μH	20-47uF	20-68uF

### Selecting the Inductor

The recommended inductor values are shown in the Application Diagram. It is important to guarantee the inductor core does not saturate during any foreseeable operational situation. The inductor should be rated to handle the peak load current plus the ripple current: Care should be taken when reviewing the different saturation current ratings that are specified by different manufacturers. Saturation current ratings are typically specified at 25°C, so ratings at maximum ambient temperature of the application should be requested from the manufacturer.

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times F_{OSC}}$$

Where  $\Delta I_L$  is the inductor ripple current. Choose inductor ripple current to be approximately 30% of the maximum load current. The maximum inductor peak current is:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$



Under light load conditions below 100mA, larger inductance is recommended for improved efficiency.

### Selecting the Output Capacitor

Special attention should be paid when selecting these components. The DC bias of these capacitors can result in a capacitance value that falls below the minimum value given in the recommended capacitor specifications table.

The ceramic capacitor's actual capacitance can vary with temperature. The capacitor type X7R, which operates over a temperature range of  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ , will only vary the capacitance to within  $\pm 15\%$ . The capacitor type X5R has a similar tolerance over a reduced temperature range of  $-55^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ . Many large value ceramic capacitors, larger than  $1\mu\text{F}$  are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from  $25^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ . Therefore X5R or X7R is recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below  $25^{\circ}\text{C}$ .

Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the  $0.47\mu\text{F}$  to  $44\mu\text{F}$  range. Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will increase about 2:1 as the temperature goes from  $25^{\circ}\text{C}$  down to  $-40^{\circ}\text{C}$ , so some guard band must be allowed.

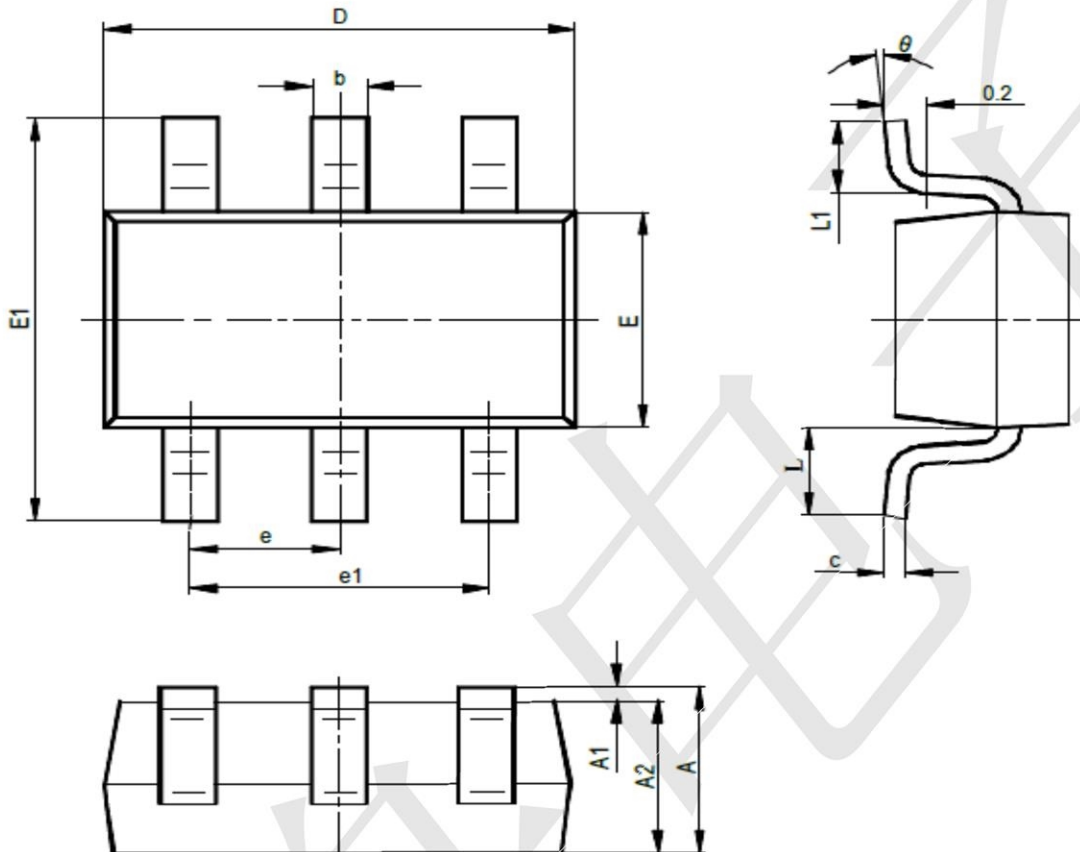
### PC Board Layout Consideration

PCB layout is very important to achieve stable operation. It is highly recommended to duplicate EVB layout for optimum performance. If change is necessary, please follow these guidelines for reference.

1. Keep the path of switching current short and minimize the loop area formed by Input capacitor, high-side MOSFET and low-side MOSFET.
2. Bypass ceramic capacitors are suggested to be put close to the Vin Pin.
3. Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
4. VOUT, SW away from sensitive analog areas such as FB.
5. Connect IN, SW, and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.



**Package information**  
SOT23-6



SYMBOL	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°